General Purpose Peak EMI Reduction IC

Functional Description

P3P8220A/AH is a versatile, 1.8V/2.5V/3.3V Peak EMI reduction IC. P3P8220A accepts an input clock from an external reference and delivers a 1x modulated clock output.

P3P8220A is a Low drive part and P3P8220AH is a High drive part. Refer to *DC/AC Electrical characteristic* table.

P3P8220A/AH operates with 1.8V/2.5V/3.3V supply and is available in an 8 Pin, WDFN (2 mm x 2 mm) Package.

General Features

- 1x, LVCMOS Peak EMI Reduction
- Supports Non-continuous Input Clock Applications
- Input / Output Frequency Range: Up to 60 MHz
- Low and High Drive Part
- Supply Voltage: 1.8 V±0.1 V
 2.5 V±0.2 V
 3.3 V±0.3 V
- 8–Pin, WDFN(2 mm x 2 mm) Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Application

• P3P8220A is Targeted Towards Consumer Electronic Applications



Figure 1. Block Diagram



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- GH = Specific Device Code
- M = Date Code
- = Pb-Free Device





ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Table 1. PIN DESCRIPTION

Pin #	Pin Name	Туре	Description			
1	CLKIN	I	External reference Clock Input			
2	NC		No connection			
3	NC		No connection			
4	GND	Р	Ground			
5	ModOUT	0	Buffered Modulated Clock output.			
6	NC		No connection			
7	NC		No connection			
8	V _{DD}	Р	1.8V/2.5V/3.3V Supply Voltage			

Table 2. OPERATING CONDITIONS

Symbol	Description	Min	Max	Unit
V _{DD}	Supply Voltage 1.8 V 2.5 V 3.3 V	1.7 2.3 3.0	1.9 2.7 3.6	V
T _A	Operating Temperature (Ambient Temperature)	0	70	°C
CL	Load Capacitance		15	pF
C _{IN}	Input Capacitance		7	pF

Table 3. ABSOLUTE MAXIMUM RATING

Symbol	Description	Rating	Unit
$V_{DD,} V_{IN}$	Voltage on any input pin with respect to Ground	–0.5 to +4.6	V
T _{STG}	Storage temperature	-65 to +125	°C
Ts	Max. Soldering Temperature (10 sec)	260	°C
TJ	Junction Temperature	150	°C
T _{DV}	Static Discharge Voltage (As per JEDEC STD22- A114-B)	2	KV

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

NOTE: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.

Symbol Parameter **Test Conditions** Min Max Unit Тур Supply Voltage V V_{DD(1.8V)} 1.7 1.8 1.9 V_{DD(2.5V)} 2.3 2.5 2.7 3 3.3 3.6 V_{DD(3.3V)} Input LOW Voltage 0.35*V_{DD} V VIL V_{IH} Input HIGH Voltage 0.65*V_{DD} V_{DD}+0.3 V V V_{OL} **Output LOW Voltage** P3P8220A 0.25*V_{DD} $V_{DD(1.8V)}, I_{OL} = 4mA$ $V_{DD(2.5V, 3.3V)}, I_{OL} = 8mA$ P3P8220AH $V_{DD(1.8V)}, I_{OL} = 6mA$ V_{DD(2.5V, 3.3V)}, I_{OL} = 12mA Output HIGH Voltage P3P8220A V VOH 0.75*V_{DD} $V_{DD(1.8V)}, I_{OL} = -4mA$ V_{DD(2.5V, 3.3V)}, I_{OL} = -8mA P3P8220AH V_{DD(1.8V)}, I_{OL} =- 6mA V_{DD(2.5V, 3.3V)}, I_{OL} = -12mA Static Supply Current CLKIN pulled LOW V_{DD(1.8V)} 1.3 mΑ I_{CC} 1.5 V_{DD(2.5V)} 1.7 V_{DD(3.3V)} **Dynamic Supply Current** 15 MHz 2.3 mΑ V_{DD(1.8V)} I_{DD} 60 MHz 6.0 V_{DD(2.5V)} 15 MHz 3.2 60 MHz 8.0 15 MHz 4.5 V_{DD(3.3V)} 60 MHz 12 pF C_L Load Capacitance 15 Z₀ **Output Impedance** P3P8220A 50 Ω V_{DD(1.8V)} P3P8220AH 30 P3P8220A 36 V_{DD(2.5V)} P3P8220AH 24 V_{DD(3.3V)} P3P8220A 30 P3P8220AH 20

Table 4. ELECTRICAL CHARACTERISTICS

Table 5. SWITCHING CHARACTERISTICS

Parameter	Test Conditions			Min	Тур	Max	Unit
Input Frequency						60	MHz
ModOUT						60	
Output Rise Time (Notes 1 & 2)	Measured between 20% to 80%	V _{DD(1.8V)}	P3P8220A		3.0	5.0	ns
			P3P8220AH		2.0	4.0	
		V _{DD(2.5V)}	P3P8220A		1.8	3.0	
			P3P8220AH		1.2	2.5	
		V _{DD(3.3V)}	P3P8220A		1.4	2.5	
			P3P8220AH		1.0	1.6	
Output Fall Time (Notes 1 & 2)	Measured between 20% to 80%	V _{DD(1.8V)}	P3P8220A		2.4	4.0	
			P3P8220AH		1.6	3.0	-
		V _{DD(2.5V)}	P3P8220A		1.8	3.0	
			P3P8220AH		1.2	2.0	
		V _{DD(3.3V)}	P3P8220A		1.4	2.0	
			P3P8220AH		1.0	1.6	
Output Duty Cycle (Notes 1, 2 & 3)	Measured at VDD/2	1		45	50	55	%
Cycle-to-Cycle Jitter (Note 1)	Unloaded spreaded output	V _{DD(1.8V)}	15 MHz		±350		ps
			60 MHz		±200		1
		V _{DD(2.5V)}	15 MHz		±500		
			60 MHz		±150		
		V _{DD(3.3V)}	15 MHz		±750		
			60 MHz		±200		
Maximum Input-Output Delay	Unloaded spreaded output	V _{DD(1.8V)}				7.5	ns
(Notes 1 & 2)		V _{DD(2.5V)}				7.5	
		V _{DD(3.3V)}				7.5	

Parameter is guaranteed by design and characterization. Not 100% tested in production.
 All parameters are specified with 15 pF loaded outputs.
 For an input Duty Cycle (typ) of 50%.

SWITCHING WAVEFORMS



Figure 5. Typical Application Circuit

NOTE: Device to Device variation of T_{skew} and I/O delay is $\pm\,20\%.$

ORDERING INFORMATION

Ordering Code	Marking	Temperature	Package Type	Shipping [†]
P3P8220AG-08CR	GH	0°C to +70°C	8–pin (2 mm x 2 mm) WDFN (Pb–Free)	Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-Free.

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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